BGY32 BGY33 BGY35 BGY36

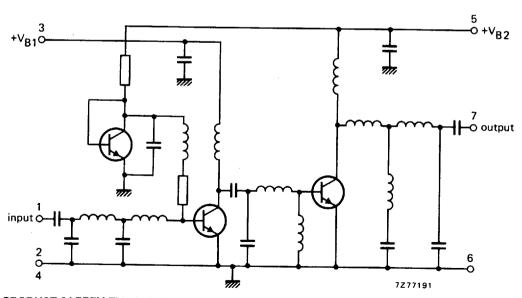
VHF POWER AMPLIFIER MODULES

A range of broadband amplifier modules designed for mobile communications equipments, operating directly from 12 V vehicle electrical systems. The devices will produce 18 W output into a 50 Ω load. The modules consist of a two stage RF amplifier using npn transistor chips, together with lumped-element matching components.

QUICK REFERENCE DATA

type number	mode of operation	frequency range f (MHz)	nominal supply voltages V _{B1} = V _{B2} (V)	power	load power PL (W)	nominal input impedance z _i (Ω)	nominal load impedance Z _L (Ω)
BGY32	cw	68 to 88	12.5	100	> 18 typ 23	50	50
BGY33	cw	80 to 108	12.5	100	> 18 typ 22	50	50
BGY35	cw	132 to 156	12.5	150	> 18 typ 22	50	50
BGY36	cw	148 to 174	12.5	150	> 18 typ 21	50	50

CIRCUIT DIAGRAM



PRODUCT SAFETY This device incorporates beryllium oxide, the dust of wich is toxic. The device is entirely safe provided that the BeO disc is not damaged.

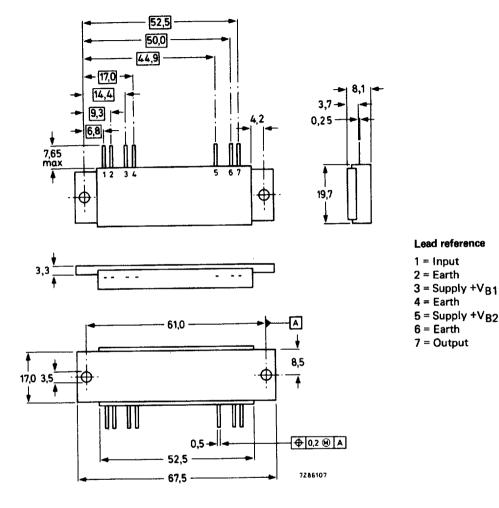
69E D

Dimensions in mm

₩ 6653931 0030212 3T3 **■**APX

MECHANICAL DATA

Fig. 1 SOT132B.



Mounting and soldering recommendations

To ensure good thermal transfer the module should be mounted using heatsink compound onto a heatsink with a flat surface; if an isolation washer is used heatsink compound should be used on both sides of the insulator. Burrs and thickening of the holes in the heatsink should be removed and 3 mm bolts tightened to torques of 0,5 Nm minimum.

Devices may be soldered directly into a circuit with a soldering iron at maximum iron temperature of 245 °C for 10 seconds at least 1 mm from the plastic.

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VHF power amplifier modules

X9A TES E150E00 16PE244

BGY32 BGY33 BGY35 BGY36

RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

DC voltages (with respect to flange)

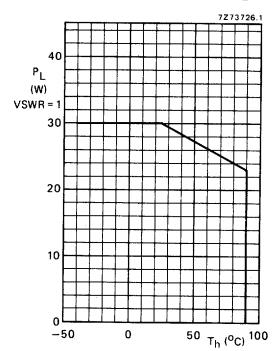
DC supply terminals RF input terminal RF output terminal

Input drive power BGY32 and BGY33 Input drive power BGY35 and BGY36

Load power

V_{B1} and V_{B2} 15 V max ±۷۱ max 25 V ±۷٥ 25 V max P_{D} max 200 mW

 P_D 300 mW max PL 30 W max



Storage temperature range Operating heatsink temperature

Tstg Th

-40 to 100 °C 90 °C

max

■ 6653931 0030214 176 **■**APX

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CHARACTERISTICS

$$T_{h} = 25 \, {}^{\circ}C$$

Quiescent current

		BGY32	BGY33	BGY35	BGY36	
I _{BQ1}	typ typ	6 13	6 13	6 13		mA mA
f	> <	68 88	80 108	132 156	1 -	MHz MHz
P _L	> typ > typ	18 23 40 50	18 22 40 50	_	- -	W W %
P _L	> typ >	- -		18 22 40 50	21 40	W W %
	I _{BΩ2} f P _L η P _L	F _{BQ2} typ	BQ1 typ 6 G IBQ2 typ 13 S S S S S S S S S	BQ1 typ 6 6 6 6 BQ2 typ 13 13	BQ1 typ	BQ1 typ

Harmonic output

Any single harmonic will be at least 25 dB down relative to carrier

Input VSWR with respect to 50 Ω

typ

1,5

Stability

The module is stable with a load VSWR up to 3:1 (all phases) when operated within the following conditions: $V_{S1} = 6$ to 15 V; $V_{S2} = 10$ to 15 V; $V_{S1} \le V_{S2}$: $P_D = 50$ to 200 mW; frequency within operating frequency range, provided the maximum ratings of the module are not exceeded.

Ruggedness

The modules are capable of withstanding load mismatch of up to 50 VSWR for short period overload conditions, with P_D , V_{B1} and V_{B2} at maximum values providing the combination does not result in the matched RF output power rating being exceeded.

APPLICATION INFORMATION

Supply

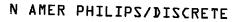
An electrolytic capacitor of 10 μ F (25 V), in parallel with a polyester capacitor of 100 nF to earth, is recommended as decoupling arrangement for each power supply pin.

Power rating

In general it is recommended that the output power from the module under nominal design conditions should not exceed 23 W in order to provide adequate safety margin under fault conditions.

Output power control

The module is not designed to be operated over a large range of output power levels. The purpose of the output power control is to set the nominal output power level. The preferred method of output power control is by varying the drive power between 50 and 200 mW. The next option is by varying V_{S1} between 6 and 12.5 V.

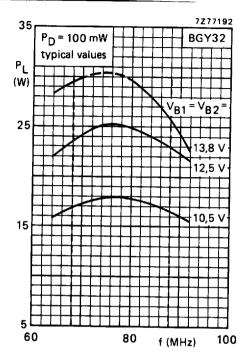


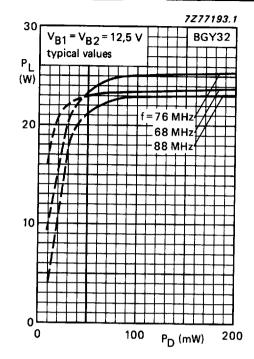
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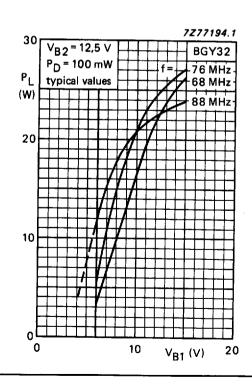
VHF power amplifier modules

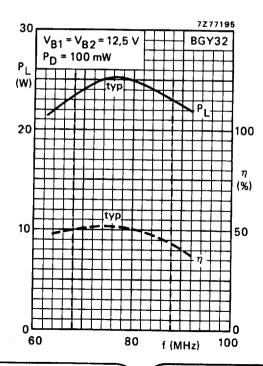
XAV = 0030512 005 = Abx

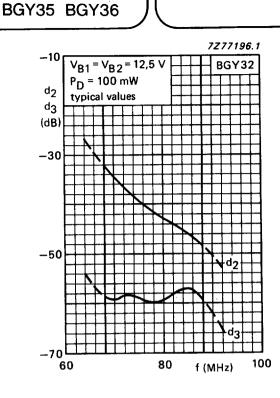
BGY32 BGY33 BGY35 BGY36

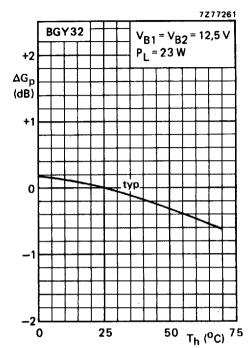


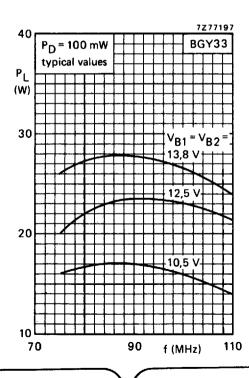


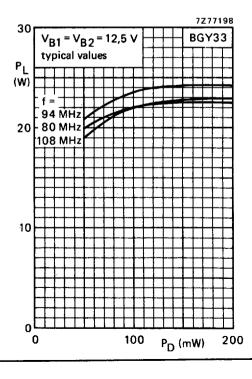


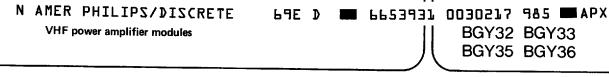


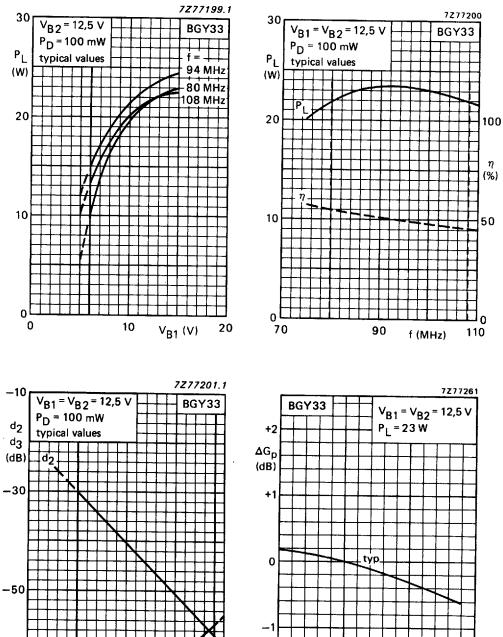












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90

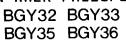
110

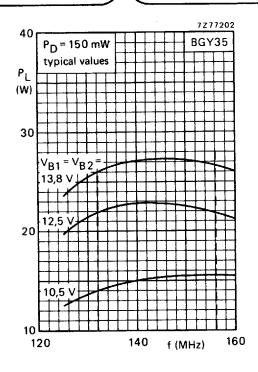
f (MHz)

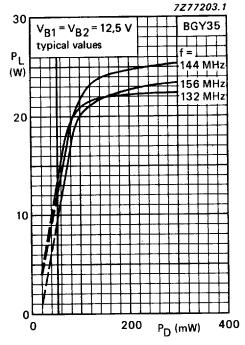
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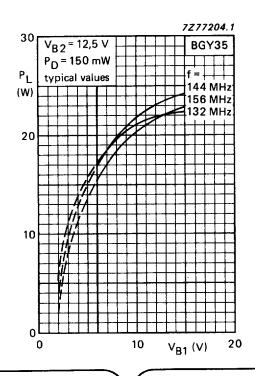
25

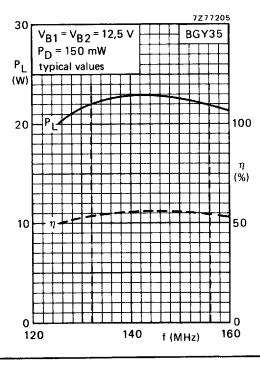
⁵⁰ T_h (°C) ⁷⁵











BGY32 BGY33 BGY35 BGY36

